

DE/2ID	HIGH EFFICIENCY RED
DE/2SRD	SUPER BRIGHT RED
DE/2YD	YELLOW
DE/2GD	GREEN
DE/2SGD	SUPER BRIGHT GREEN

Features

- UNIFORM LIGHT EMITTING AREA.
- EASILY MOUNTED ON P.C. BOARDS OR INDUSTRY STANDARD SOCKETS.
- FLUSH MOUNTABLE.
- EXCELLENT ON/OFF CONTRAST.
- CAN BE USED WITH PANELS AND LEGEND MOUNTS.
- MECHANICALLY RUGGED.
- I.C. COMPATIBLE.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

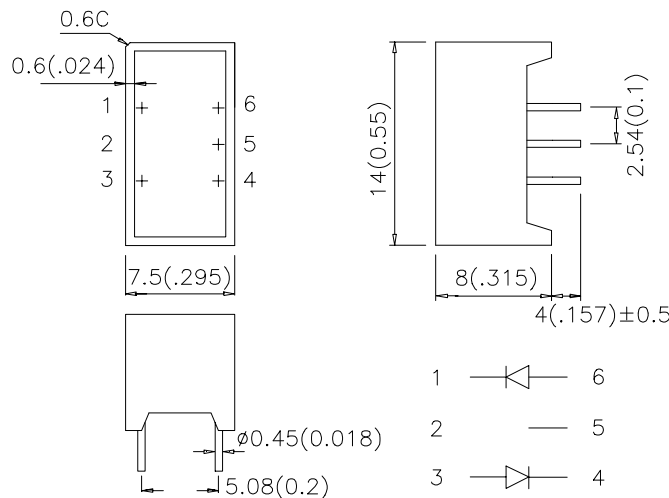
The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

The Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

The Super Bright Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 10 mA *20mA		Viewing Angle
			Min.	Typ.	2θ1/2
DE/2ID	HIGH EFFICIENCY RED (GaAsP/GaP)	RED DIFFUSED	9	31	120°
DE/2SRD	SUPER BRIGHT RED (GaAlAs)	RED DIFFUSED	*100	*300	120°
DE/2YD	YELLOW(GaAsP/GaP)	YELLOW DIFFUSED	9	31	120°
DE/2GD	GREEN (GaP)	GREEN DIFFUSED	9	52	120°
DE/2SGD	SUPER BRIGHT GREEN (GaP)	GREEN DIFFUSED	*40	*80	120°

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 20mA..

Electrical / Optical Characteristics at T_A=25°C

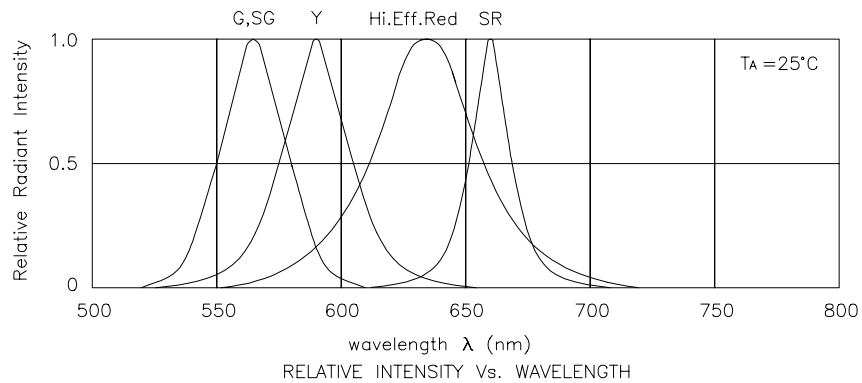
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	High Efficiency Red Super Bright Red Yellow Green Super Bright Green	627 660 590 565 565		nm	I _F =20mA
λ _D	Dominate Wavelength	High Efficiency Red Super Bright Red Yellow Green Super Bright Green	625 640 588 568 568		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	High Efficiency Red Super Bright Red Yellow Green Super Bright Green	45 20 35 30 30		nm	I _F =20mA
C	Capacitance	High Efficiency Red Super Bright Red Yellow Green Super Bright Green	15 45 20 15 15		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	High Efficiency Red Super Bright Red Yellow Green Super Bright Green	2.0 1.85 2.1 2.2 2.2	2.5 2.5 2.5 2.5 2.5	V	I _F =20mA
I _R	Reverse Current	All		10	uA	V _R = 5V

Absolute Maximum Ratings at $T_A=25^\circ\text{C}$

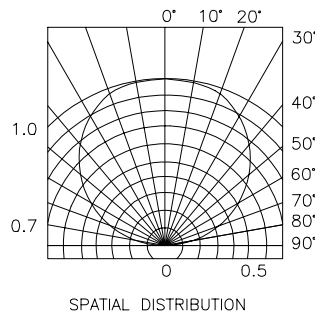
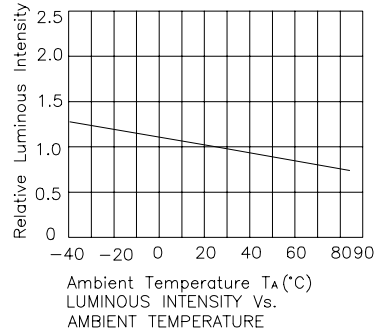
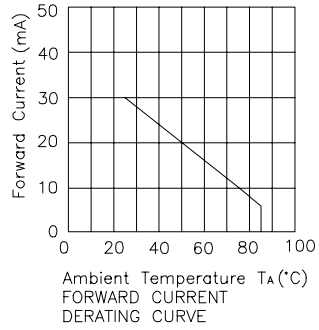
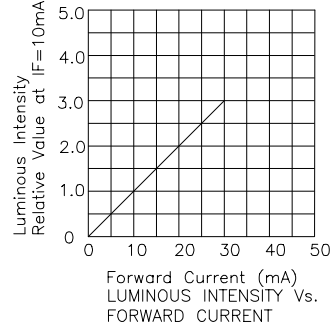
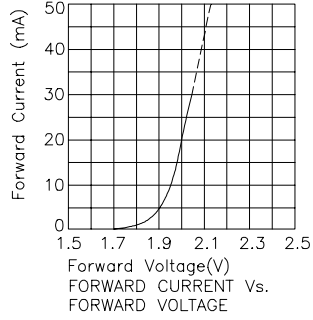
Parameter	High Efficiency Red	Super Bright Red	Yellow	Green	Super Bright Green	Units
Power dissipation	105	100	105	105	105	mW
DC Forward Current	30	30	30	25	25	mA
Peak Forward Current [1]	160	155	140	140	140	mA
Reverse Voltage	5	5	5	5	5	V
Operating/Storage Temperature	-40°C To +85°C					
Lead Solder Temperature [2]	260°C For 5 Seconds					

Notes:

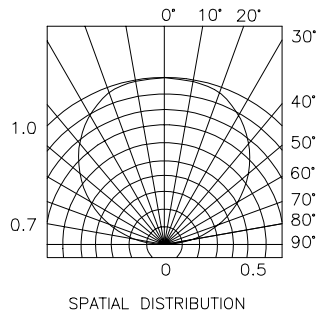
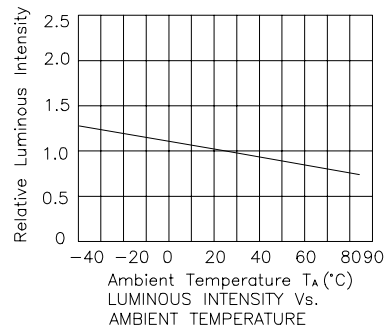
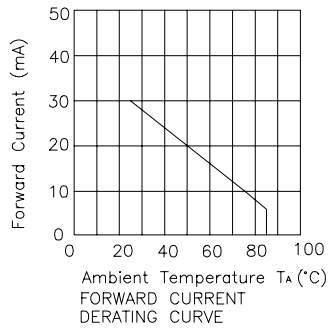
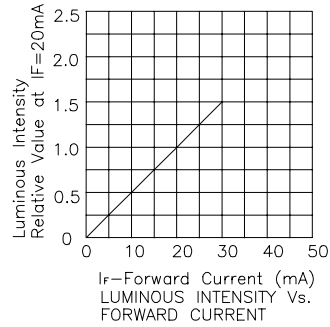
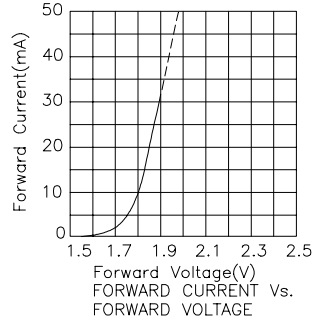
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



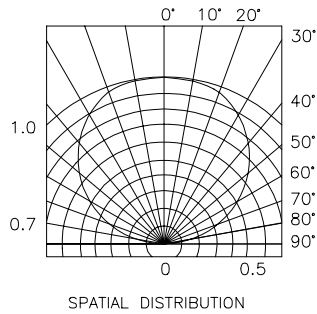
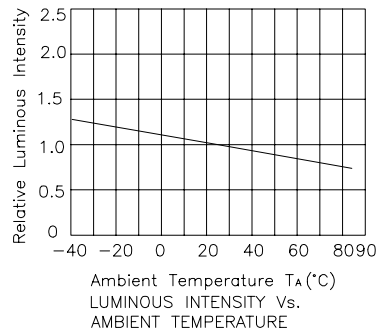
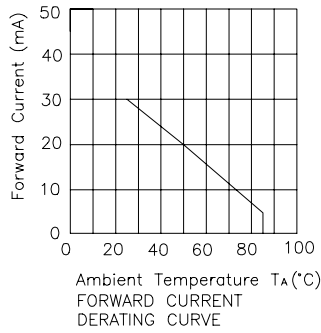
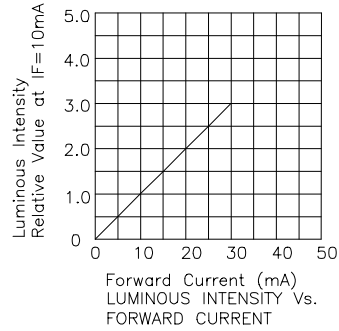
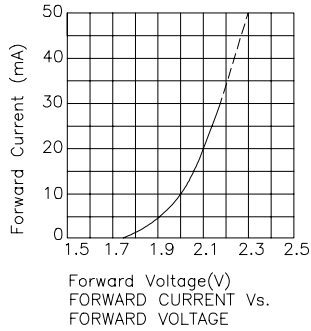
High Efficiency Red



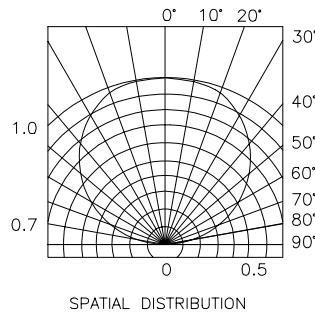
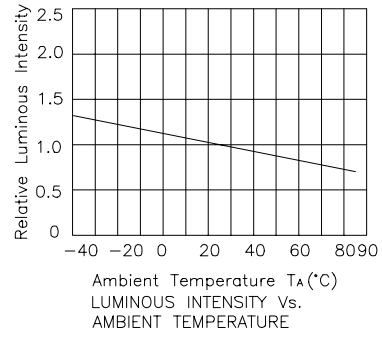
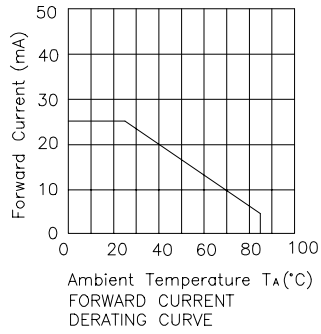
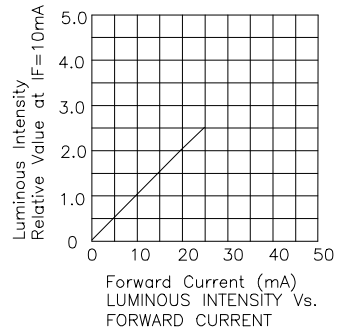
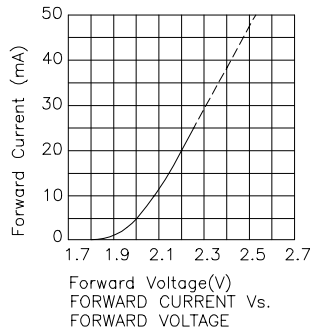
Super Bright Red



Yellow



Green



Super Bright Green

